GT5182

2A, Synchronous Step-Down DC-DC Converter

Advanced

1. Features

- High Efficiency: Up to 95%
- Up to 2A Output Current
- Very Low Shutdown Current: 20μA at maximum input supply voltage
- Integrated 0.12Ω Switch
- Operating Switching Frequency from 350kHz to 2MHz
- 4.75V to 18V Input Voltage Range
- Programmable Output Voltage from 0.9V to 16V.
- Current Mode Operation with External Compensation for Optimized Loop Bandwidth
- Internal Soft Start
- Over Temperature Shutdown
- Cycle-by-Cycle Over Current Protection
- Programmable Under Voltage Lockout
- Operating Temperature: -40℃ to +85℃
- 8-Pin SOP Package and HSOP Package

2. General Description

The GT5182 device is a high efficiency monolithic synchronous step-down bulk regulator using current mode architecture with two integrated power MOSFETs. This device delivers up to 2A of output current over a wide operating voltage supply range from 4.75V to 18V which makes this device ideally suited for many applications such as battery powered systems, distributed power systems, networking systems and green electronics/appliances. Current mode operation provides fast transient response and excellent load and line regulation.

The switching frequency is adjustable from 350kHz to 2.0MHz, allowing the use of different sizes surface mount inductors and capacitors.

The fault condition protections such as cycle-by-cycle current limiting and over temperature hysteretic shutdown are implemented. In shutdown mode the converter draws 20μA of supply current at the maximum input supply voltage. Additional features include soft start, and enable.

The GT5182 is available in an 8-Pin SOP package and thermal enhanced HSOP package.

3. Applications

- Networking systems
- Battery-Powered Systems
- Distributed Power Systems
- Pre-regulator for Linear Regulators

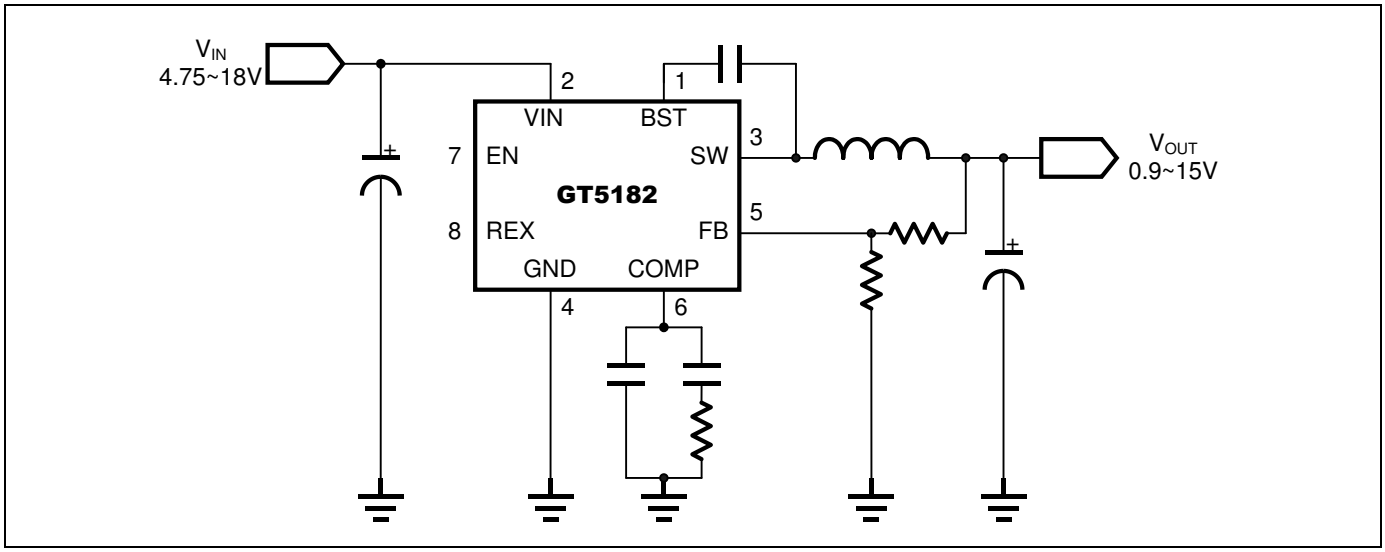


Figure 1. Typical Application Circuit

4. Functional Block Diagram

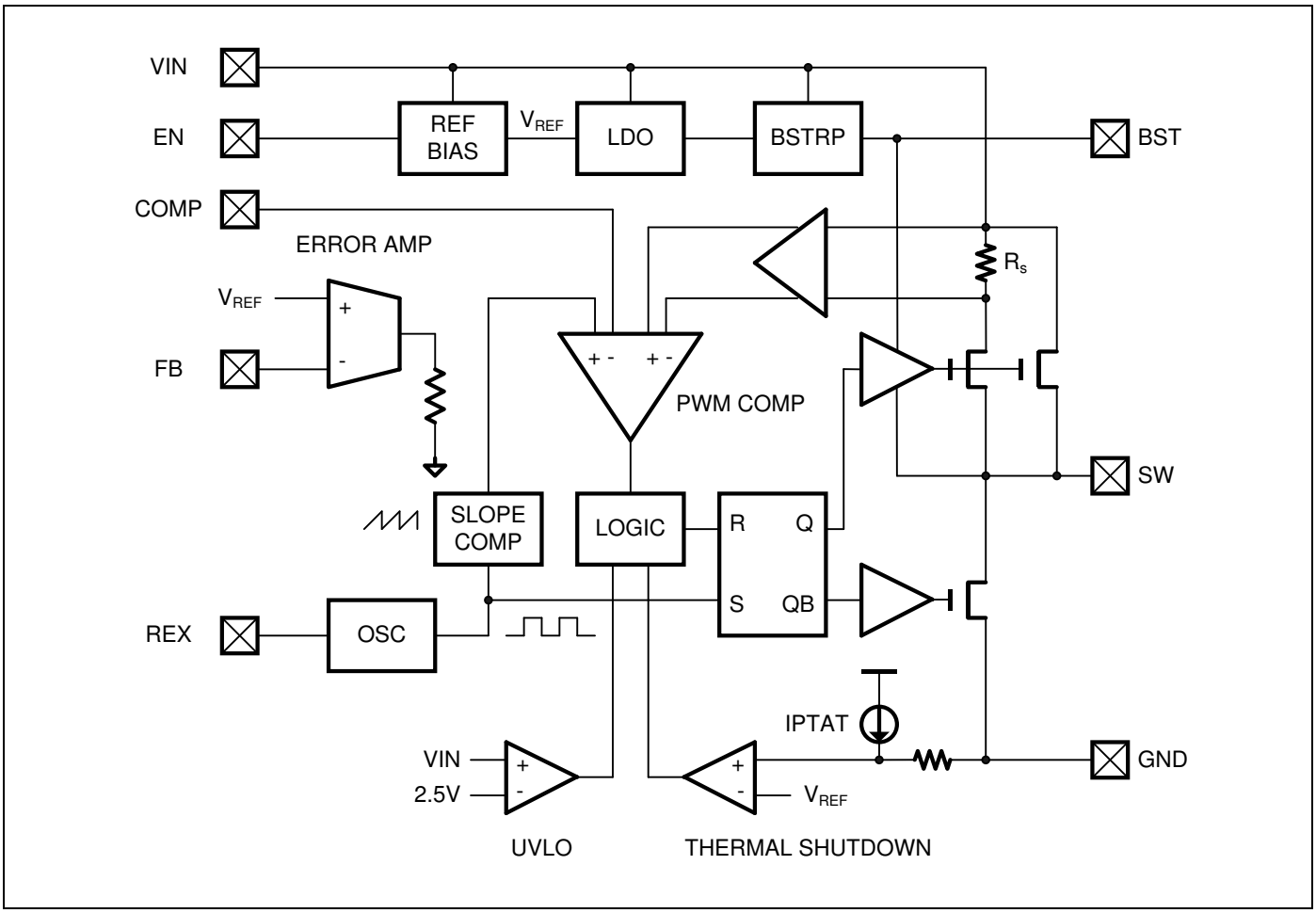


Figure 2. Current Mode Buck Converter

5. Pin Configuration

5.1 SOP8 (Top View)

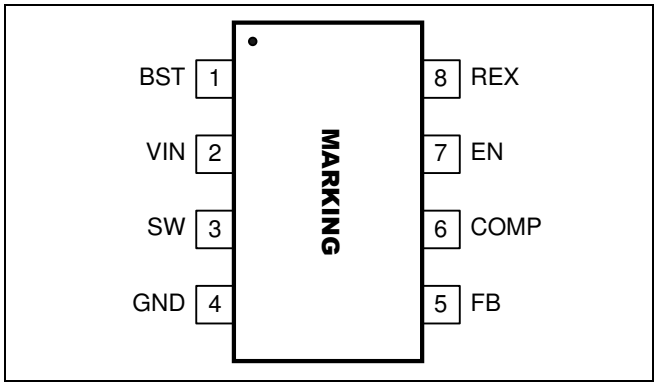


Figure 3. Pin Assignment Diagram (SOP8 Package)

5.2 HSOP8 (Top View)

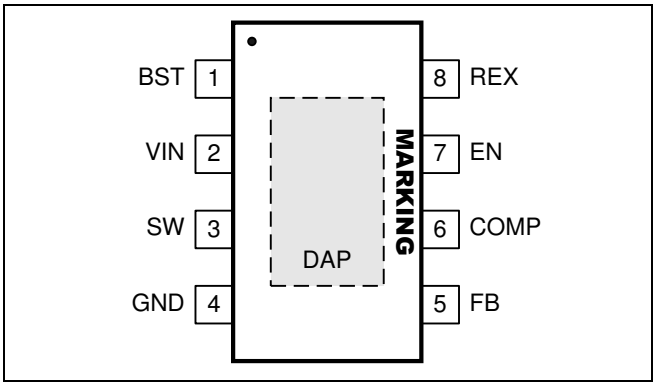


Figure 4. Pin Assignment Diagram (HSOP8 Package)

Note: Please see section "**Part Markings**" for detailed Marking Information.

5.3 Pin Descriptions

Pin No.	Name	I/O	Function
1	BST	I	A 2~10nF ceramic capacitor is connected from this pin to the SW pin to drive the power switch's gate above Bootstrap the power supply voltage.
2	VIN	-	Supply. Connect this pin to a supply voltage from 4.75V to 18V
3	SW	O	Switching node for the converter. Connect inductor to this node.
4	GND	-	Ground. This pin is the voltage reference for the regulated output voltage.
5	FB	I	Feedback. An external resistor divider sets the output voltage.
6	COMP	I	Compensation. Connect a compensation network to stable the loop and optimize the loop bandwidth.
7	EN	I	Enable. Pull down to ground to turn-off the converter. Leave EN open if it is unused.
8	REX	I	Setting of internal Oscillator frequency. A resistor is connected from REX to GND to set the Oscillator frequency from 350 kHz to 2.0 MHz

6. Functional Description

6.1 Operation

The GT5182 uses current mode PWM step-down architecture with internal top and bottom power switches. The switching frequency of the regulator is variable from 350kHz to 2MHz set by external resistor connected at REX pin. The default switching frequency is 350kHz.

The operating description is referring to functional bloc diagram (***Figure 1***). During normal operation, the rising edge of internal oscillator clock sets the RS latch and the top NMOS switch is turned on each switching cycle. The inductor current is sensed and amplified by current sense amplifier. Ramp compensation is summed to the error amplifier output and compare to the COMP pin voltage with PWM comparator. The output of PWM comparator resets the RS latch, turns off the top NMOS switch until next cycle and turn on the bottom NMOS switch. During the off-time of top NMOS switch, inductor current discharges through bottom MNOS switch, which ensures the bootstrap capacitor fully charged during DCM mode.

When voltage of FB pin exceeds 20% the normal regulation voltage of 0.9V, the over voltage comparator is tripped and turn off the high-side-switch.

6.2 Enable

Logic low EN forces the GT5182 into shut down mode. In shutdown, this device only draws 20μA supply current at maximum supply voltage.

6.3 Soft Start

Soft-start function of GT5182 limits the inrush current during start-up, and eliminates possible voltage drops of the input voltage when a battery or a high-impedance power source is connect to the GT5182. Typical start-up time is about 750μs.

6.4 Short-Circuit Protection

The frequency of the oscillator is reduced to 1/4 of the normal frequency when the output is shorted to ground. This function ensures enough time for inductor current to decay.

6.5 Thermal Shutdown

The device goes into thermal shutdown mode when the junction temperature exceeds 150℃. It continues normal operation when the temperature falls below 120℃.

6.6 Boost Function

A 1~10nF capacitor C_{BOOST} is used to generate a voltage V_{BOOST} to drive the gate of top NMOS switch above the supply voltage. The voltage across this capacitor is about 5V.

6.7 Under Voltage Lockout

The under voltage lockout circuit prevents the device from miss operation at low-input voltages. It turns off the switches under undefined conditions. The minimum input voltage to start up the GT5182 is 4.5V and device will shut down at 2.5V.

7. Theory or operation/design procedure

7.1 Inductor Selection

There are two main considerations when selecting optimal inductors. First, the inductor should not saturate, and second, the inductor current ripple should be small enough to achieve the desired output voltage ripple. The dc resistance of the inductance directly influences the efficiency of the converter. Therefore, an inductor with lowest dc resistance should be selected for highest efficiency.

In order to avoid saturation of the inductor, the inductor should be rated at least for the maximum output current plus the inductor ripple current which is calculated as:

$$I_{PEAK} = I_{LOAD} + \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{2L \times f \times V_{IN}} \quad (1)$$

Where

f= Switching frequency (350kHz typical)

L= Inductor value

Table 1: Recommended Components for Standard Output Voltages

F_S V_{OUT}	1.5	1.8	2.5	3.3	5	12
default	6.8µH	10µH	10µH	15µH	22µH	33µH
800kHz	2.8µH	3.6µH	4.7µH	6.2µH	8.2µH	15µH
1.25MHz	1.8µH	2.2µH	2.8µH	3.7µH	5.1µH	8.8µH

7.2 Output Capacitor Selection

A 22µF (typical) output capacitor is needed with a 6.8µH inductor. Ceramic capacitors with low ESR are used for the lowest output voltage ripple.

The overall output ripple voltage is the sum of the voltage spike caused by the output ESR plus the voltage ripple caused by charge and discharging the output capacitor

$$V_{RIPPLE} = V_{OUT} \times \frac{1 - \frac{V_{OUT}}{V_{IN}}}{L \times f} \times \left(\frac{1}{8 \times C_{OUT} \times f} + R_{ESR}\right) \quad (2)$$

The largest output voltage ripple occurs at the highest input voltage.

7.3 Input Capacitor Selection

In continuous mode, the input current to the device is discontinuous, therefore a low ESR input capacitor is required for best input voltage filtering and minimizing the interference with other circuits caused by high input voltage spikes. This capacitor should have a minimum value of 10µF.

Since it absorbs the input switching current it requires an adequate ripple current rating. Its RMS current rating should be greater than approximately 1/2 of the output current.

For insuring stable operation the capacitor should be placed as close to the IC possible.

7.5 Feedback divider resistors to set output voltage - R2, R1

The output voltage is set by R2 and R1, $V_{OUT} = 0.9 \times (1 + R_2 / R_1)$. 10kΩ is a good typical value, and can be as high as 100kΩ. Too high impedance can make feedback node prone to noise injection particularly if unshielded inductors are used.

7.6 Frequency selection

The frequency is set by external R_{EXT} and internal resistor as $f_s = 350k \times [1 + 300k / R_{EXT})]$

7.7 Stability compensation

Follow the following steps to compensate the IC:

STEP 1: set the cross over frequency at 1/10 of the switching frequency

$$fc = Gcs \times Gea \times Rcomp \times \frac{V_{ref}}{Vout} \times \frac{1}{2\pi \times Cout} \quad (3)$$

$$Rcomp = \frac{2\pi \times Cout}{Gcs \times Gea \times \frac{V_{ref}}{Vout}} \times \frac{1}{10} \times fs \quad (4)$$

STEP 2: set the zero fz1 at 1/4 frequency of the cross over frequency.

$$Ccomp = \frac{1}{2\pi Rcomp \times \frac{1}{40} \times fs} \quad (5)$$

STEP 3: If the output capacitors' ESR is high enough to cause a zero at lower than 4 times the cross frequency, an additional compensation capacitor Ccomp2 is required, and the proper value is

$$Ccomp2 = \frac{CoutR_{ESR}}{Rcomp} \quad (6)$$

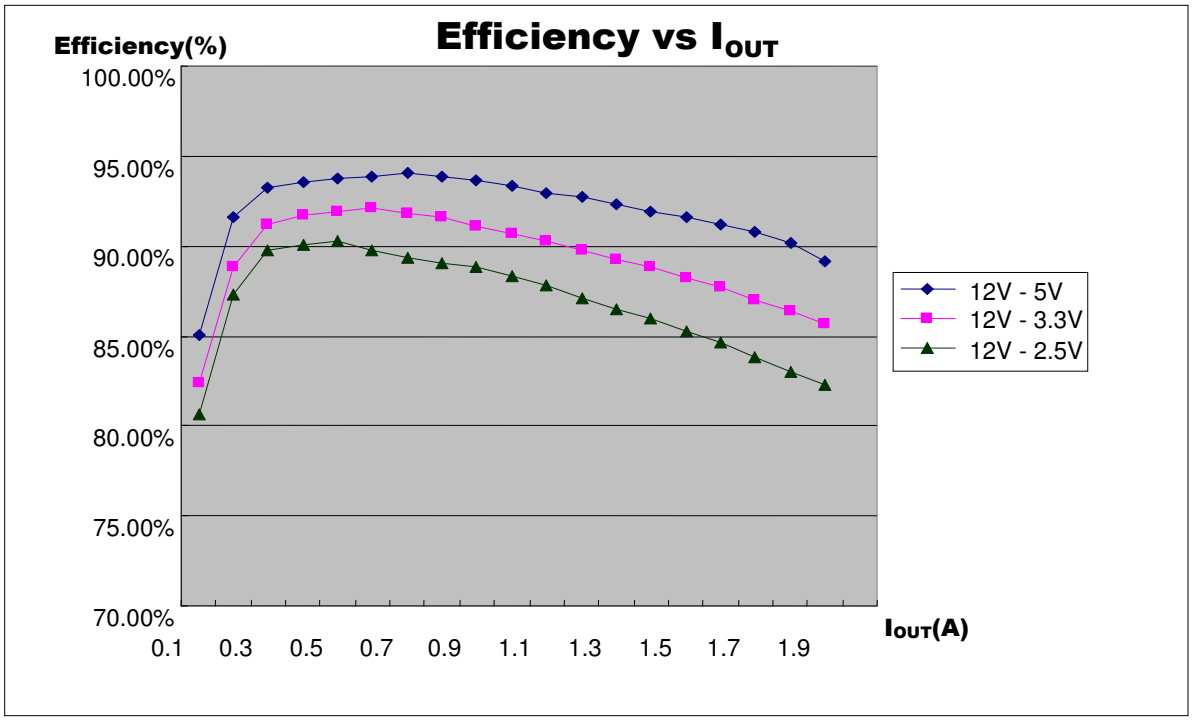


Figure 5. Efficiency vs. Load Current

8. Electrical Characteristics

8.1 Absolute Maximum Ratings

Condition	Min	Max
Supply Voltage (V_{IN})	-0.3V	18V
Switch Voltage (V_{SW})	-1.0V	V_{IN}+1V
Bootstrap Voltage (V_{BST})	V_{SW}-0.3V	Vsw+6V
Feedback Voltage (V_{FB})	-0.3V	6V
Enable Voltage (V_{EN})	-0.3V	6V
Comp Voltage (V_{COMP})	-0.3V	6V
OSC Voltage (V_{OSC})	-0.3V	6V
Operating Junction Temperature	-40℃	150℃
Storage Temperature	-55℃	150℃
Lead Temperature		300℃

Note: Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

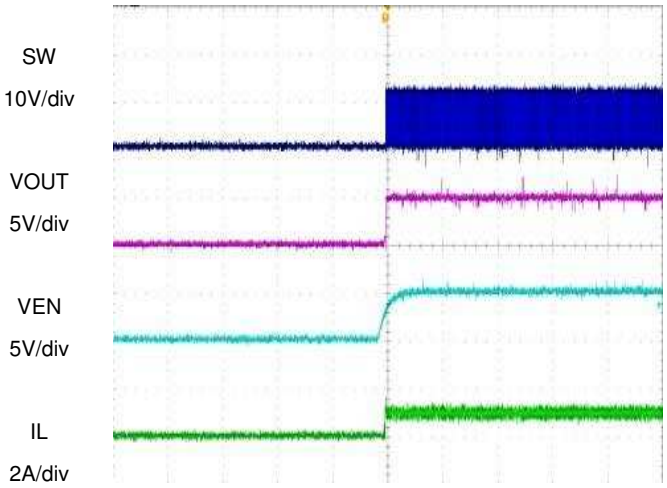
8.2 Electrical Characteristics

Electrical Characteristics (V_{IN}=12V, T_A=25℃ unless otherwise specified)

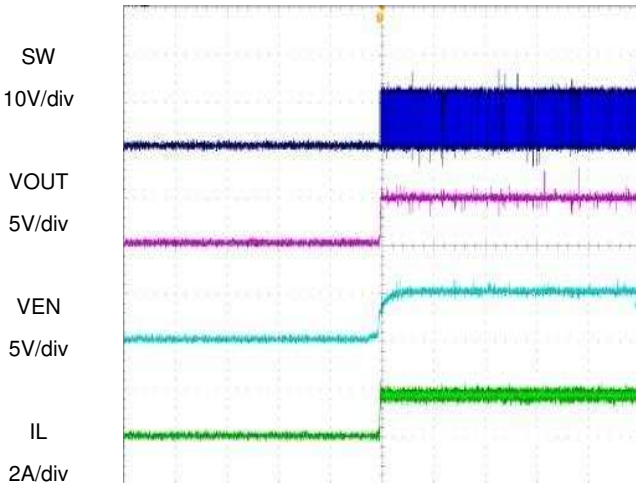
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Input Voltage Range	V_{IN}		4.75		18	V
Supply Quiescent Current	I_Q	V_{IN}=12V	-	1.0	-	mA
Supply Shutdown Current	I_{SHDN}	V_{EN}=0V	-	10	20	μA
Feedback Voltage	V_{FB}	4.75≤V_{IN}≤18V, V_{COMP}<2V	0.895	0.910	0.925	V
HS Switch On Resistance	R_{ONH}	I_{SW}=100mA	-	0.12	-	Ω
LS Switch On Resistance	R_{ONL}	I_{SW}=100mA	-	0.12	-	Ω
Internal Switch Leakage	I_{LEAK}	V_{EN}=0, V_{DS}=18V	-	-	10	μA
HS Switch Current Limit	I_{LIMH}		2.5	3.4	-	A
LS Switch Current Limit	I_{LIML}	From drain to source	-	1.1	-	A
COMP to Current Sense Transconductance	G_{CS}		-	3.5	-	A/V
Error Amplifier DC Gain	A_{VEA}		-	4000	-	V/V
Error Amplifier Transconductance	G_{EA}	ΔI_{COMP}=±10μA	-	800	-	μA/V
Switching Frequency	f_{SW}		-	350	-	kHz
Switching Frequency	f_{SW_SET}	R_{OSC}=80 kΩ	1125	1250	1375	kHz
Short Circuit Frequency		V_{FB}=0V	-	f_{SW}/8	-	kHz
Maximum Duty Cycle	D_{MAX}	V_{FB}=1.0V	-	90	-	%
Minimum on Time	$t_{ON(MIN)}$		-	150	-	ns
Enable Threshold Voltages	V_{IH}		0.6	0.85	1.2	V
Under Voltage Lockout Threshold Rising	V_{UVLO}		2.4	2.5	2.6	V
Under Voltage Lockout Threshold Hysteresis	V_{UVL_TH}		-	150	-	mV
Thermal Shutdown Temperature	T_{SHDN}		-	150	-	℃
Thermal Shutdown Temperature Hysteresis			-	40	-	℃

8.3 Typical characteristics

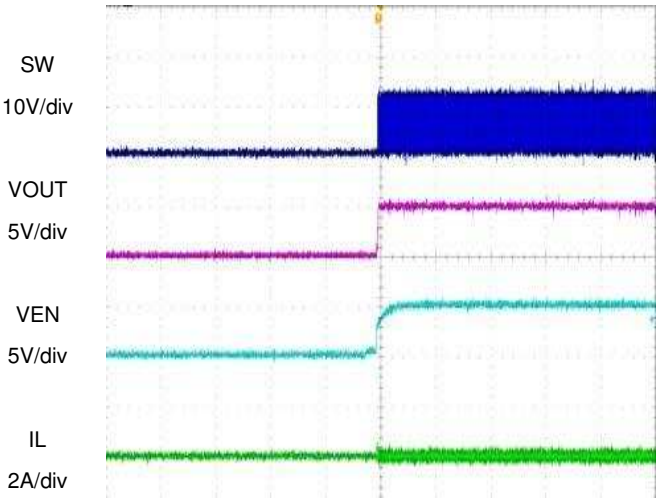
Start up through Enable at 1A load



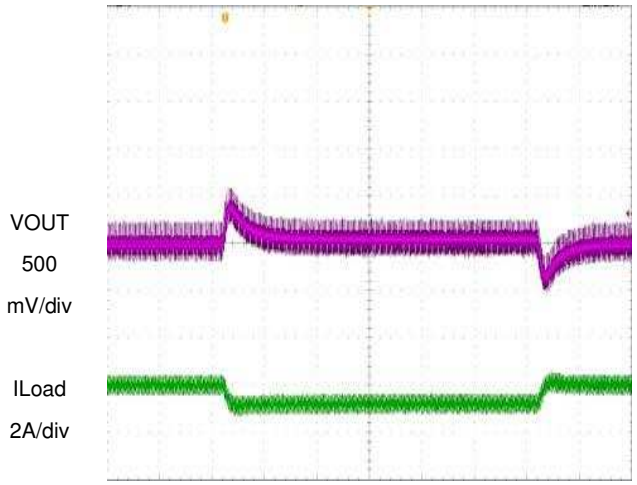
Start up through Enable at 2A load



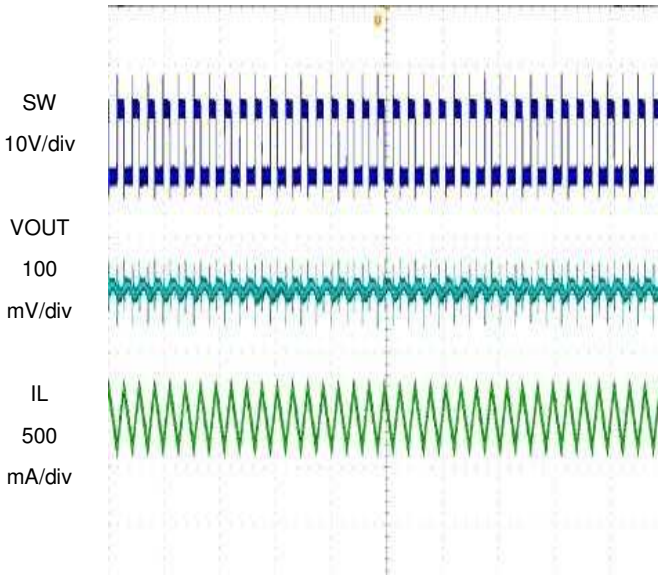
Start up through Enable without Load



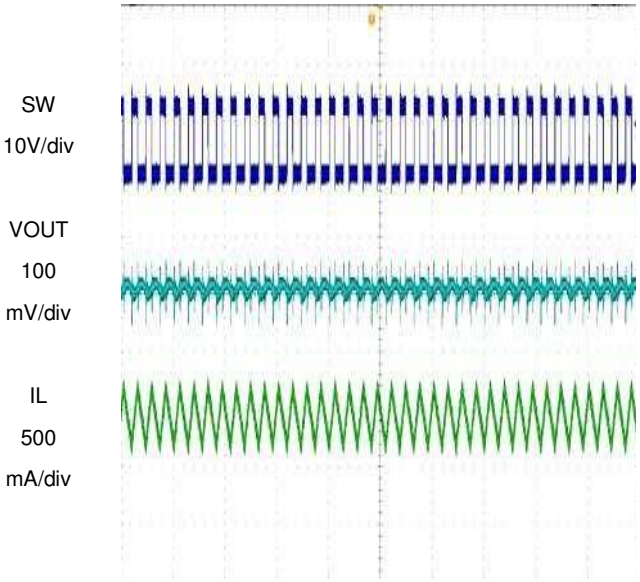
Load transition(1A to 2A)



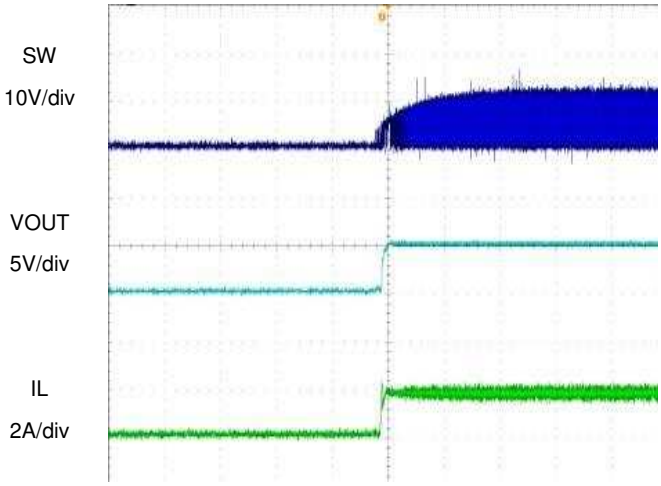
Full Load operation



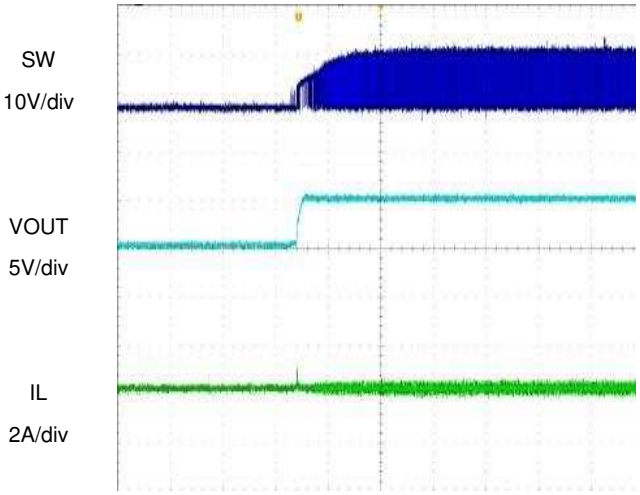
Operation without Load



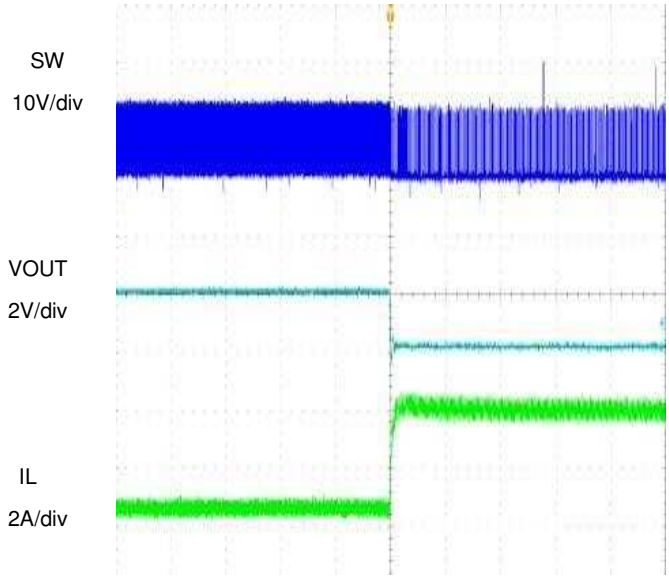
Soft-start at 2A Load



Soft-start without Load

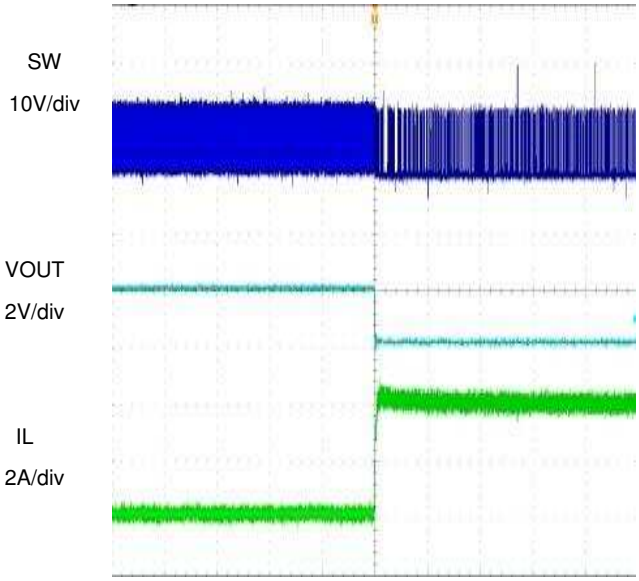


V_{OUT} Short to GND at 0.5A Load



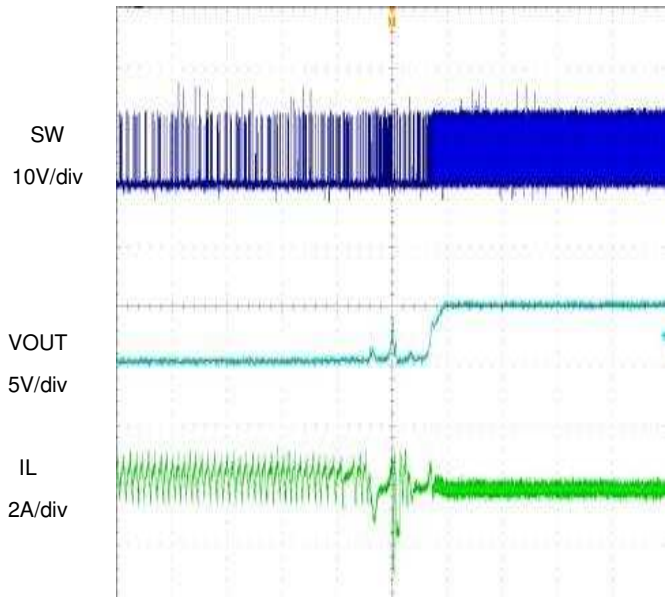
400µs/div

V_{OUT} Short to GND without Load



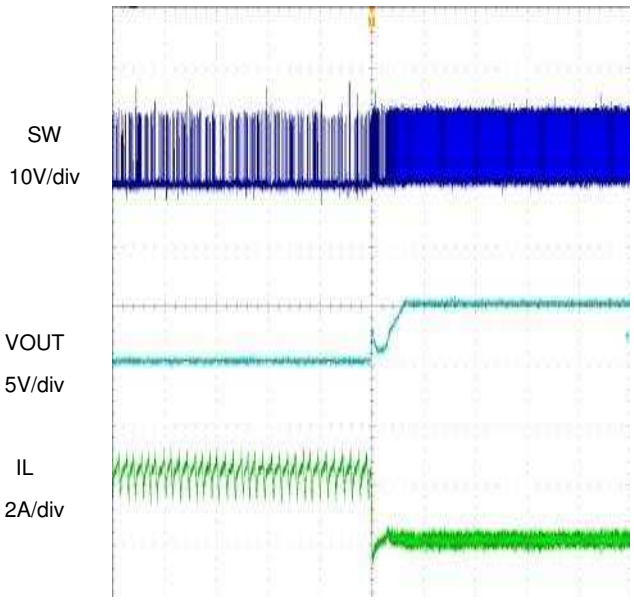
1ms/div

V_{OUT} Short Recovery at 2A Load



1ms/div

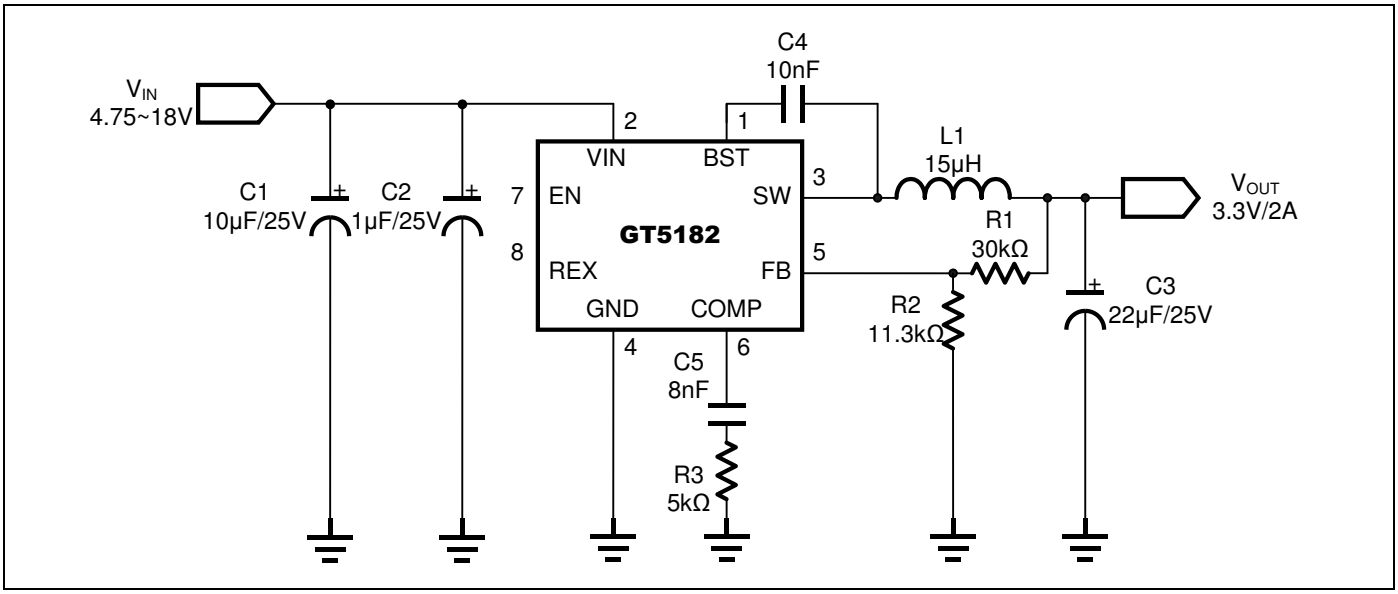
V_{OUT} Short Recovery with 0.5A Load



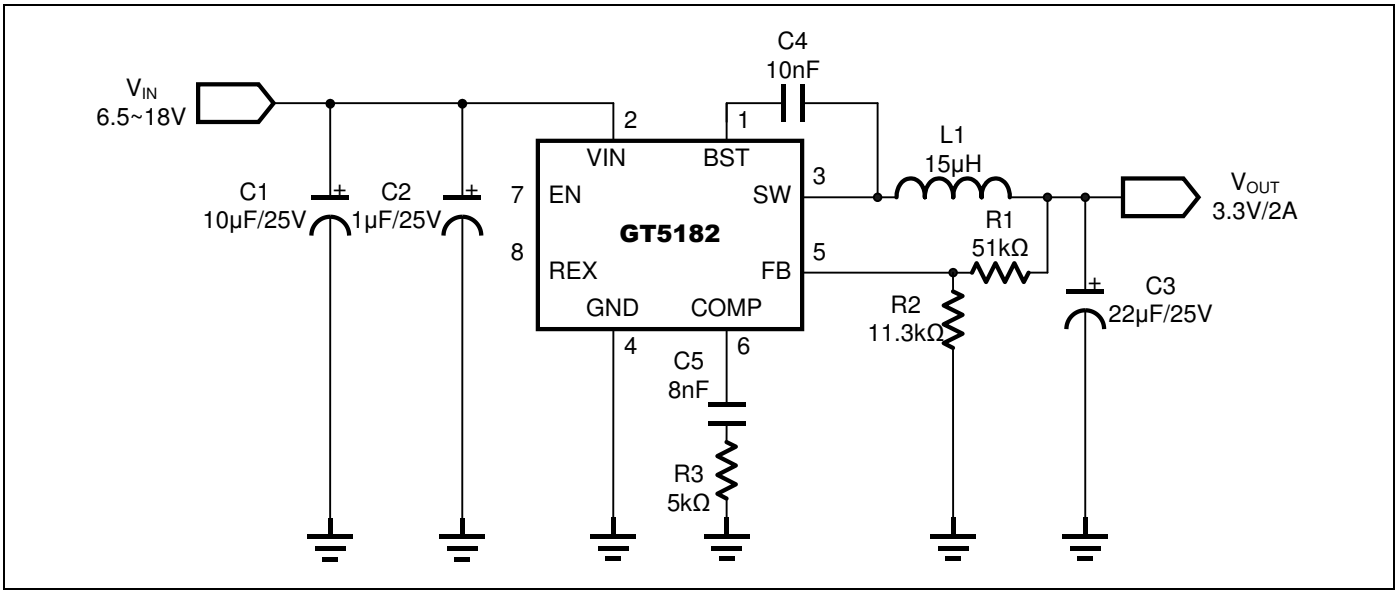
1ms/div

9. Typical Application Circuits

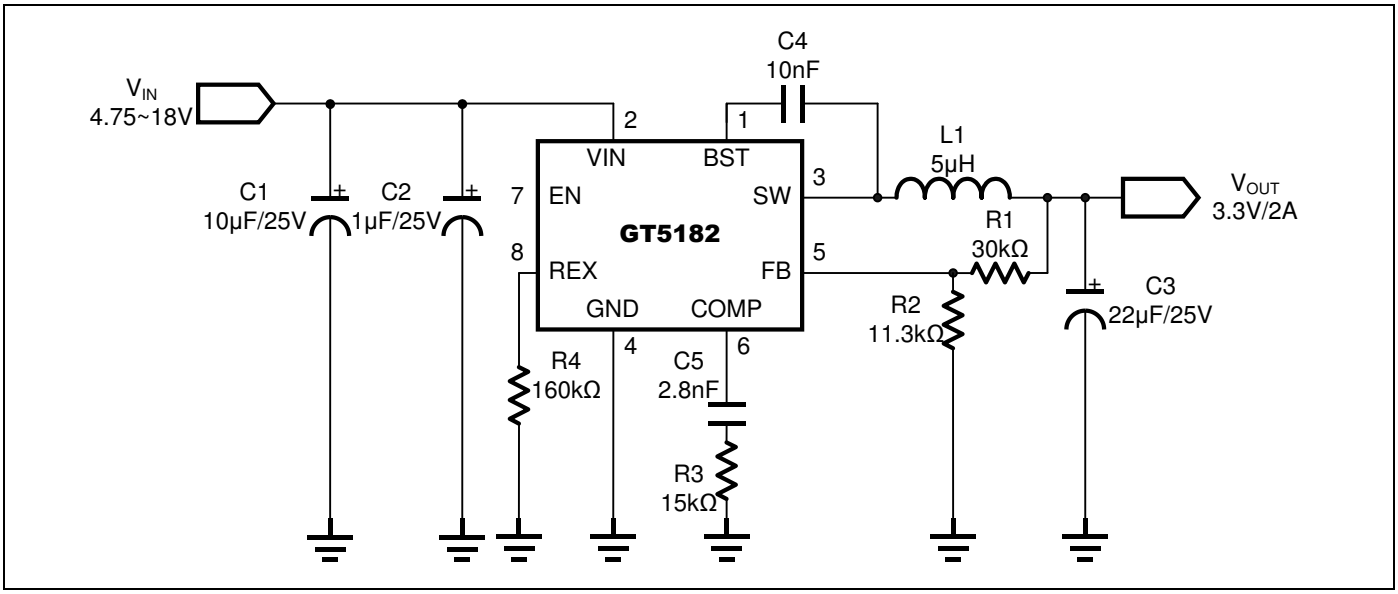
9.1 V_{OUT}=3.3V, I_{LOAD}=2A, f_{SW}=350kHz



9.2 V_{OUT}=5V, I_{LOAD}=2A, f_{SW} =350kHz



9.3 V_{OUT}=3.3V, I_{LOAD}=2A, f_{SW} =1MHz



10. Ordering Information

GT XX XX - XX X X

Temperature Range

Bank Commercial: 0℃~70℃
I Industrial: -40℃~85℃

Pb Status

G GREEN

Package Type:

G SOP
H HSOP

Part Number

Production Family

51 Power Management Product; DC-DC

Giantec Prefix

GT Giantec

Order Number	Package Description	Package Option
GT5182-GGI-TR	5.1 x 4 mm SOP8	Tape and Reel 4000
GT5182-HGI-TR	5.1 x 4 mm HSOP8	Tape and Reel 4000

11. Part Markings

11.1 GT5182-GGI (Top View)

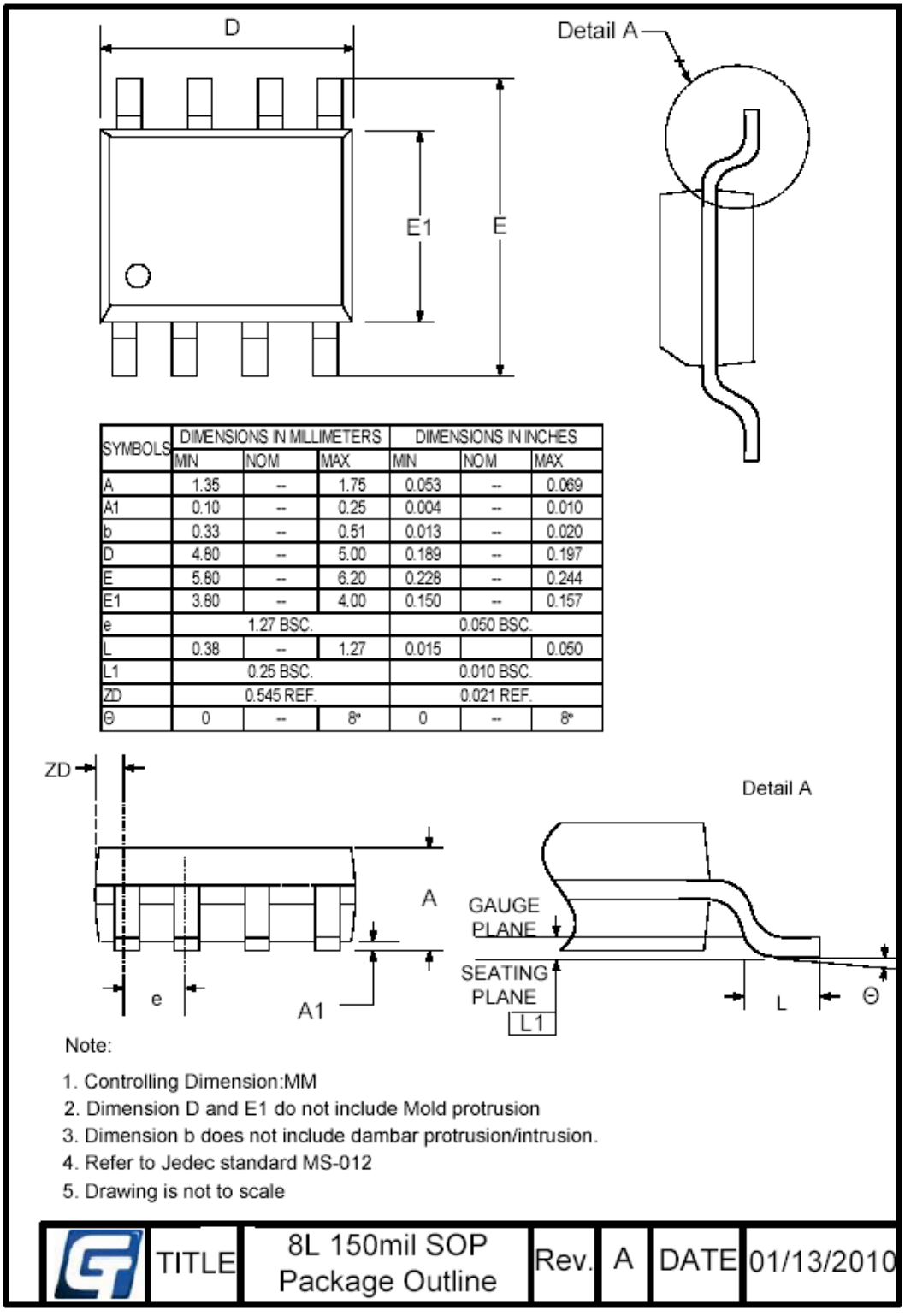
G	T	5	1	8	2	G	G	I
				Lot Number				
●		Y	Y	W	W	S	V	

GT5182GGI

Lot Number	States the last 9 characters of the wafer lot information
●	Pin 1 Indicator
YY	Seal Year
	00 = 2000
	01 = 2001
	99 = 2099
WW	Seal Week
	01 = Week 1
	02 = Week 2
	.
	.
	.
	51 = Week 51
	52 = Week 52
S	Subcon Code
	J = ASESH
	L = ASEKS
V	Die Version

12. Package Information

12.1 SOP8



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.35	--	1.75	0.053	--	0.069
A1	0.10	--	0.25	0.004	--	0.010
b	0.33	--	0.51	0.013	--	0.020
D	4.80	--	5.00	0.189	--	0.197
E	5.80	--	6.20	0.228	--	0.244
E1	3.80	--	4.00	0.150	--	0.157
e	1.27 BSC.			0.050 BSC.		
L	0.38	--	1.27	0.015		0.050
L1	0.25 BSC.			0.010 BSC.		
ZD	0.545 REF.			0.021 REF.		
Θ	0	--	8°	0	--	8°

Note:

1. Controlling Dimension:MM
2. Dimension D and E1 do not include Mold protrusion
3. Dimension b does not include dambar protrusion/intrusion.
4. Refer to Jedec standard MS-012
5. Drawing is not to scale

	TITLE	8L 150mil SOP Package Outline	Rev.	A	DATE	01/13/2010

13. Revision History

Revision	Date	Descriptions
A1	May,2011	Release Version
A0	Nov, 2010	Initial Version